

SN74ALVCHS162830

1-BIT TO 2-BIT ADDRESS DRIVER WITH 3-STATE OUTPUTS

SCES097F – APRIL 1997 – REVISED JUNE 1999

- Member of the Texas Instruments *Widebus™* Family
- *EPIC™* (Enhanced-Performance Implanted CMOS) Submicron Process
- Output Ports Have Equivalent 26- Ω Series Resistors, So No External Resistors Are Required
- Diodes on Inputs Clamp Overshoot
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Packaged in Thin Very Small-Outline Package

NOTE: For order entry:
The DBB package is abbreviated to G.

For tape and reel:
The DBBR package is abbreviated to GR.

description

This 1-bit to 2-bit address driver is designed for 2.3-V to 3.6-V V_{CC} operation.

Diodes to V_{CC} have been added on the inputs to clamp overshoot.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The outputs, which are designed to sink up to 12 mA, include equivalent 26- Ω series resistors to reduce overshoot and undershoot.

To ensure the high-impedance state during power up or power down, the output-enable (\overline{OE}) input should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74ALVCHS162830 is characterized for operation from -40°C to 85°C .

DBB PACKAGE (TOP VIEW)

2Y2	1	80	1Y3
1Y2	2	79	2Y3
GND	3	78	GND
2Y1	4	77	1Y4
1Y1	5	76	2Y4
V_{CC}	6	75	V_{CC}
A1	7	74	1Y5
A2	8	73	2Y5
GND	9	72	GND
A3	10	71	1Y6
A4	11	70	2Y6
GND	12	69	GND
A5	13	68	1Y7
A6	14	67	2Y7
V_{CC}	15	66	V_{CC}
A7	16	65	1Y8
A8	17	64	2Y8
GND	18	63	GND
A9	19	62	1Y9
$\overline{OE1}$	20	61	2Y9
$\overline{OE2}$	21	60	1Y10
A10	22	59	2Y10
GND	23	58	GND
A11	24	57	1Y11
A12	25	56	2Y11
V_{CC}	26	55	V_{CC}
A13	27	54	1Y12
A14	28	53	2Y12
GND	29	52	GND
A15	30	51	1Y13
A16	31	50	2Y13
GND	32	49	GND
A17	33	48	1Y14
A18	34	47	2Y14
V_{CC}	35	46	V_{CC}
2Y18	36	45	1Y15
1Y18	37	44	2Y15
GND	38	43	GND
2Y17	39	42	1Y16
1Y17	40	41	2Y16



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SN74ALVCHS162830

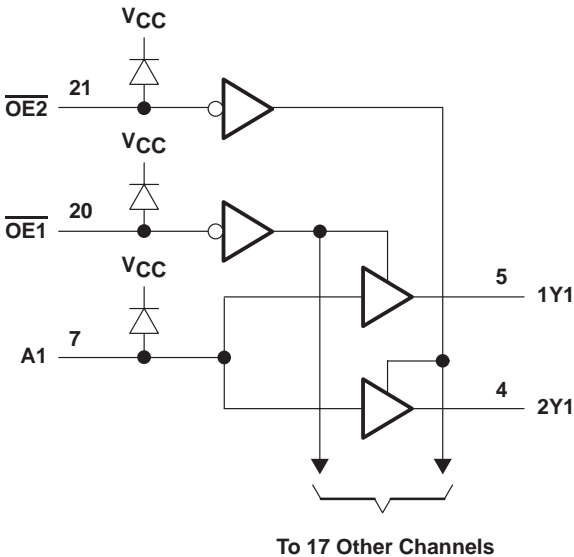
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FUNCTION TABLE				
INPUTS			OUTPUTS	
OE1	OE2	A	1Yn	2Yn
L	H	H	H	Z
L	H	L	L	Z
H	L	H	Z	H
H	L	L	Z	L
L	L	H	H	H
L	L	L	L	L
H	H	X	Z	Z

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	–0.5 V to 4.6 V
Input voltage range, V_I (see Note 1)	–0.5 V to 4.6 V
Output voltage range, V_O (see Notes 1 and 2)	–0.5 V to $V_{CC} + 0.5$ V
Input clamp current, I_{IK} ($V_I < 0$)	–50 mA
Output clamp current, I_{OK} ($V_O < 0$)	–50 mA
Continuous output current, I_O	±50 mA
Continuous current through each V_{CC} or GND	±100 mA
Package thermal impedance, θ_{JA} (see Note 3)	106°C/W
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. This value is limited to 4.6 V maximum.

3. The package thermal impedance is calculated in accordance with JESD 51.

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recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2.3	3.6	V
V _{IH}	High-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.7		V
		V _{CC} = 2.7 V to 3.6 V	2		
V _{IL}	Low-level input voltage	V _{CC} = 2.3 V to 2.7 V		0.7	V
		V _{CC} = 2.7 V to 3.6 V		0.8	
V _I	Input voltage		0	V _{CC}	V
V _O	Output voltage		0	V _{CC}	V
I _{OH}	High-level output current	V _{CC} = 2.3 V		–6	mA
		V _{CC} = 2.7 V		–8	
		V _{CC} = 3 V		–12	
I _{OL}	Low-level output current	V _{CC} = 2.3 V		6	mA
		V _{CC} = 2.7 V		8	
		V _{CC} = 3 V		12	
Δt/Δv	Input transition rise or fall rate			10	ns/V
T _A	Operating free-air temperature		–40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CC}	MIN	TYP†	MAX	UNIT
V _{IK}		I _I = −18 mA	2.3 V			−1.2	V
		I _I = 18 mA	2.3 V			V _{CC} +1.2	
V _{OH}		I _{OH} = −100 μA	2.3 V to 3.6 V			V _{CC} −0.2	V
		I _{OH} = −4 mA, V _{IH} = 1.7 V	2.3 V			1.9	
	I _{OH} = −6 mA	V _{IH} = 1.7 V	2.3 V			1.7	
		V _{IH} = 2 V	3 V			2.4	
		I _{OH} = −8 mA, V _{IH} = 2 V	2.7 V			2	
		I _{OH} = −12 mA, V _{IH} = 2 V	3 V			2	
V _{OL}		I _{OL} = 100 μA	2.3 V to 3.6 V			0.2	V
		I _{OL} = 4 mA, V _{IL} = 0.7 V	2.3 V			0.4	
	I _{OL} = 6 mA	V _{IL} = 0.7 V	2.3 V			0.55	
		V _{IL} = 0.8 V	3 V			0.55	
		I _{OL} = 8 mA, V _{IL} = 0.8 V	2.7 V			0.6	
		I _{OL} = 12 mA, V _{IL} = 0.8 V	3 V			0.8	
I _I		V _I = V _{CC} or GND	3.6 V			±5	μA
I _I (hold)		V _I = 0.7 V	2.3 V			45	μA
		V _I = 1.7 V	2.3 V			−45	
		V _I = 0.8 V	3 V			75	
		V _I = 2 V	3 V			−75	
		V _I = 0 to 3.6 V‡	3.6 V			±500	
I _{OZ}		V _O = V _{CC} or GND	3.6 V			±10	μA
I _{CC}		V _I = V _{CC} or GND, I _O = 0	3.6 V			40	μA
ΔI _{CC}		One input at V _{CC} − 0.6 V, Other inputs at V _{CC} or GND	3 V to 3.6 V			750	μA
C _i	Control inputs	V _I = V _{CC} or GND	3.3 V	5.5		pF	
	Data inputs			7			
C _O	Outputs	V _O = V _{CC} or GND	3.3 V	7.5		pF	

† All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

‡ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 and 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A	Y	1.2	3.8		4	1.7	3.5	ns
t _{en}	$\overline{\text{OE}}$	Y	1	5.7		5.7	1	4.8	ns
t _{dis}	$\overline{\text{OE}}$	Y	1	4.9		5.4	1.7	5.2	ns

operating characteristics, T_A = 25°C

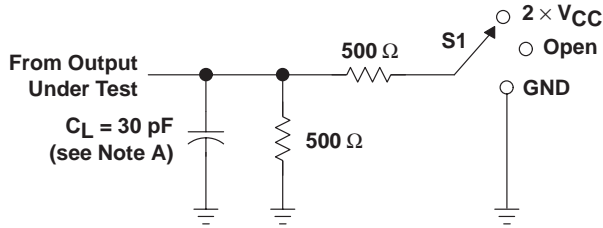
PARAMETER			TEST CONDITIONS	V _{CC} = 2.5 V ± 0.2 V	V _{CC} = 3.3 V ± 0.3 V	UNIT
				TYP	TYP	
C _{pd}	Power dissipation capacitance per driver	All outputs enabled	C _L = 0, f = 10 MHz	49	53	pF
		All outputs disabled		6	7.5	



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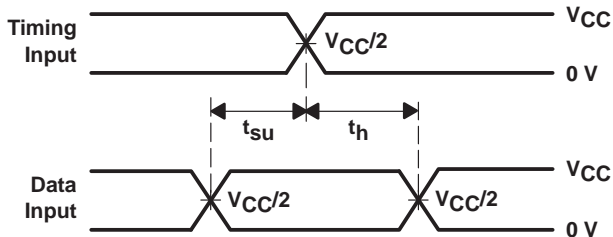
PARAMETER MEASUREMENT INFORMATION

$$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$$

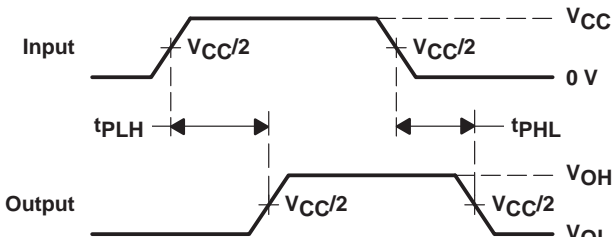


LOAD CIRCUIT

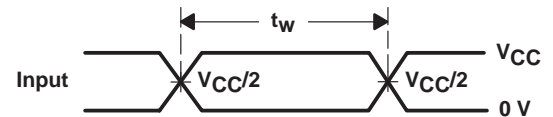
TEST	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	2 $\times V_{CC}$
t_{PHZ}/t_{PZH}	GND



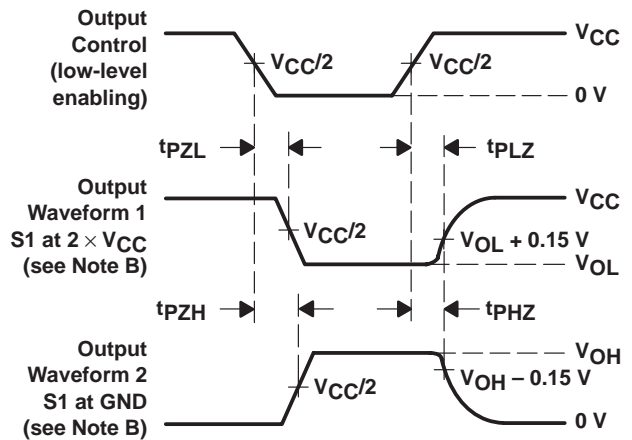
VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

- NOTES: A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2 \text{ ns}$, $t_f \leq 2 \text{ ns}$.
- D. The outputs are measured one at a time with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms

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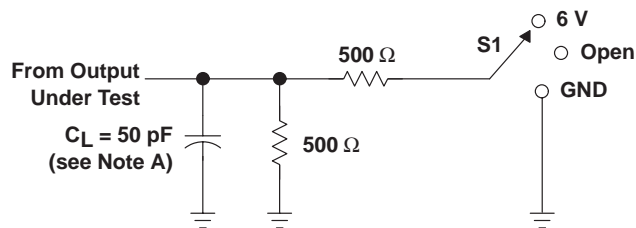
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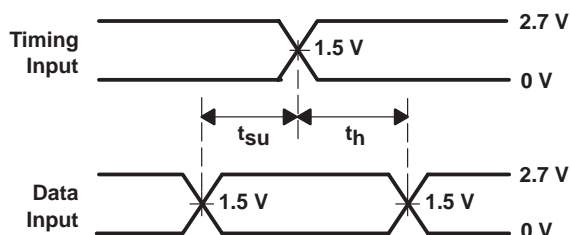
PARAMETER MEASUREMENT INFORMATION

$V_{CC} = 2.7\text{ V AND } 3.3\text{ V} \pm 0.3\text{ V}$

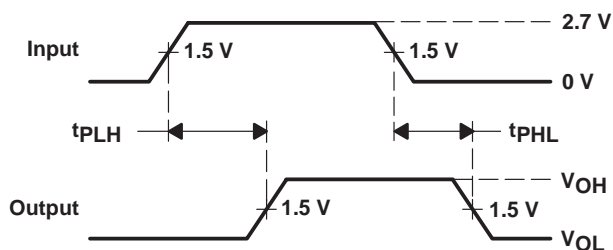


LOAD CIRCUIT

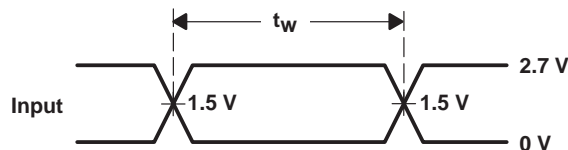
TEST	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	6 V
t_{PHZ}/t_{PZH}	GND



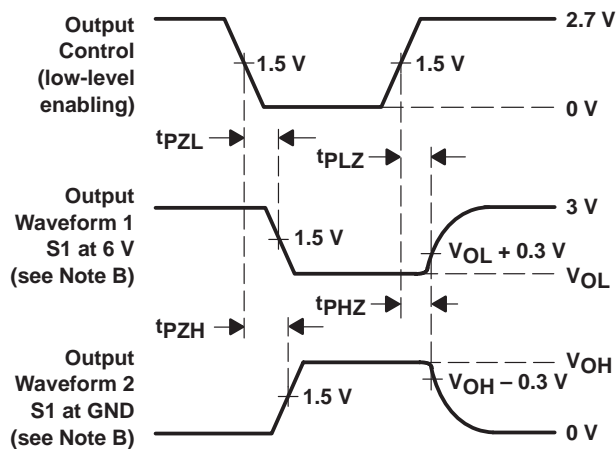
VOLTAGE WAVEFORMS
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VOLTAGE WAVEFORMS
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 - All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r \leq 2.5\text{ ns}$, $t_f \leq 2.5\text{ ns}$.
 - The outputs are measured one at a time with one transition per measurement.
 - t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - t_{PZL} and t_{PZH} are the same as t_{en} .
 - t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 2. Load Circuit and Voltage Waveforms

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- Техническая поддержка проекта;
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